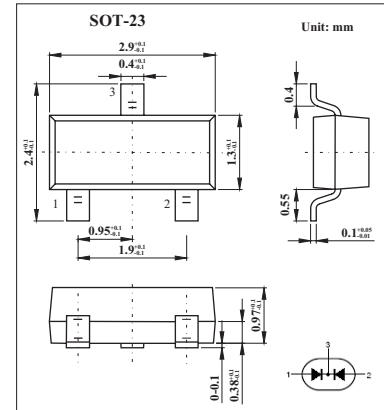


High-Speed Double Diode

KAV70(BAV70)

■ Features

- Small plastic SMD package
- High switching speed: max.4 ns
- Repetitive peak forward current: max. 450 mA



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}	85	V
Continuous reverse voltage	V_R	75	V
Continuous forward current (single diode loaded *) (double diode loaded *)	I_F	215 125	mA
Repetitive peak forward current	I_{FRM}	450	mA
Non-repetitive peak forward current ($T_j = 25^\circ\text{C}$) $t = 1\mu\text{s}$	I_{FSM}	4	A
$t = 1\text{ms}$		1	
$t = 1\text{s}$		0.5	
power dissipation ($T_{amb} = 25^\circ\text{C}$) *	P_D	250	mW
thermal resistance from junction to tie-point	$R_{th\ j-tp}$	360	K/W
thermal resistance from junction to ambient *	$R_{th\ j-a}$	500	K/W
Storage temperature	T_{stg}	-65 to +150	$^\circ\text{C}$
Junction temperature	T_j	150	$^\circ\text{C}$

* Device mounted on an FR4 printed-circuit board.

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

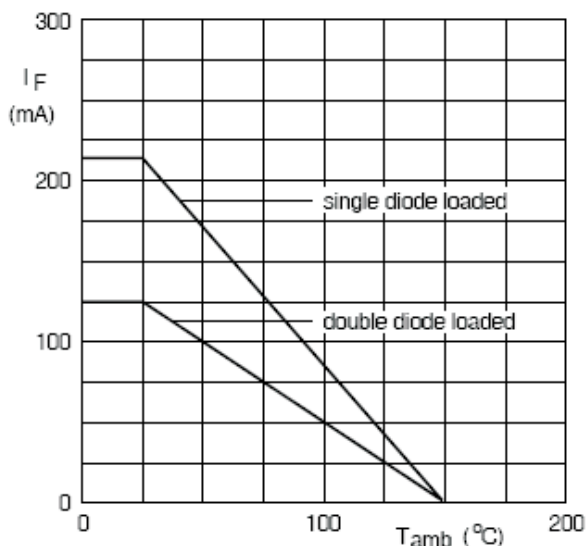
Parameter	Symbol	Conditions	Max	Unit
Forward voltage	V_F	$I_F = 1\text{ mA}$	715	mV
		$I_F = 10\text{ mA}$	855	mV
		$I_F = 50\text{ mA}$	1	V
		$I_F = 150\text{ mA}$	1.25	V
Reverse current	I_R	$V_R = 25\text{ V}$	30	nA
		$V_R = 75\text{ V}$	2.5	μA
		$V_R = 25\text{ V}; T_j = 150^\circ\text{C}$	60	μA
		$V_R = 75\text{ V}; T_j = 150^\circ\text{C}$	100	μA
Diode capacitance	C_d	$f = 1\text{ MHz}; V_R = 0\text{ V};$	1.5	pF
Reverse recovery time	t_{rr}	when switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA};$ $R_L = 100\ \Omega$; measured at $I_R = 1\text{ mA};$	4	ns
forward recovery voltage	V_{fr}	when switched from $I_F = 10\text{ mA}; t_r = 20\text{ ns};$	1.75	V

■ Marking

Marking	A4
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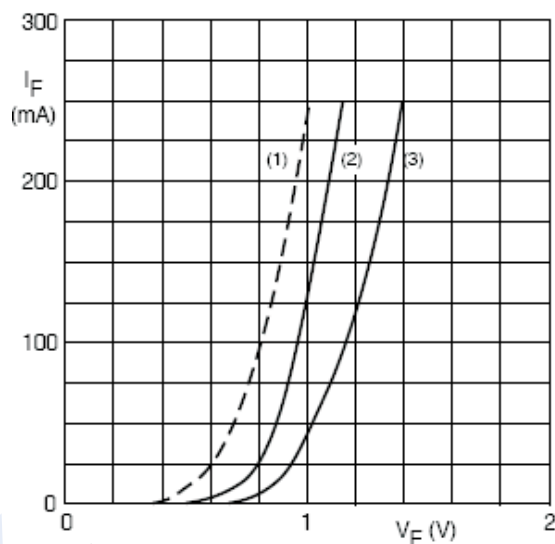
KAV70(BAV70)

■ Typical Characteristics



Device mounted on an FR4 printed-circuit board.

Fig.1 Maximum permissible continuous forward current as a function of ambient temperature.

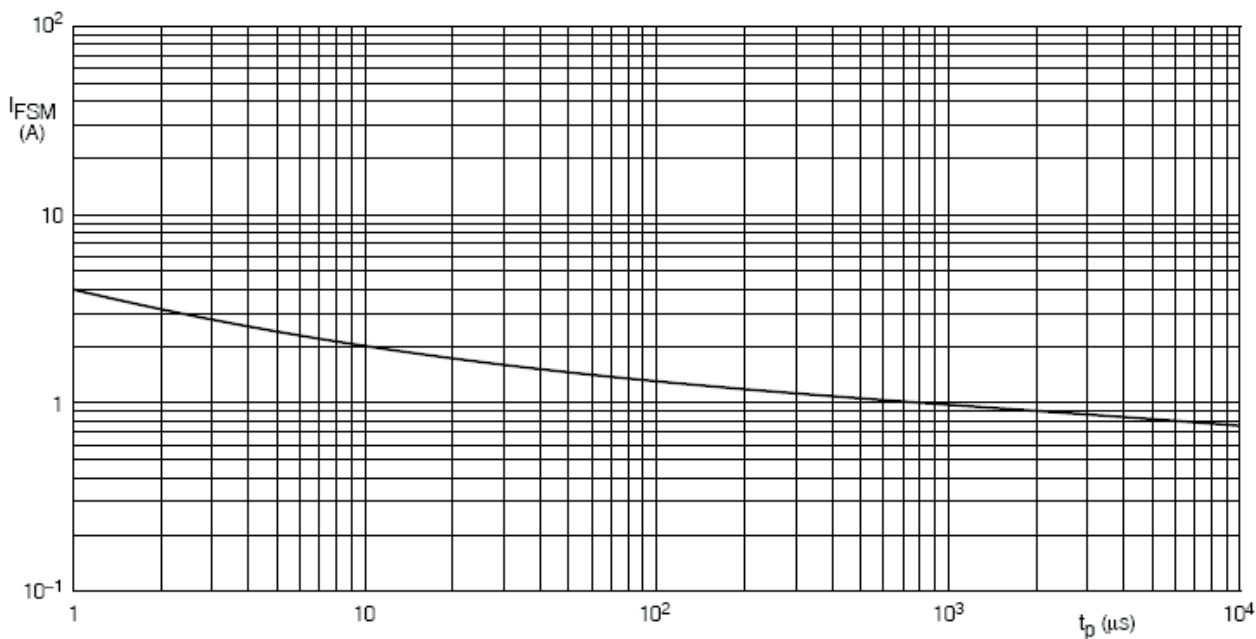


(1) $T_J = 150^\circ\text{C}$; typical values.

(2) $T_J = 25^\circ\text{C}$; typical values.

(3) $T_J = 25^\circ\text{C}$; maximum values.

Fig.2 Forward current as a function of forward voltage.



Based on square wave currents.

$T_J = 25^\circ\text{C}$ prior to surge.

Fig.3 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

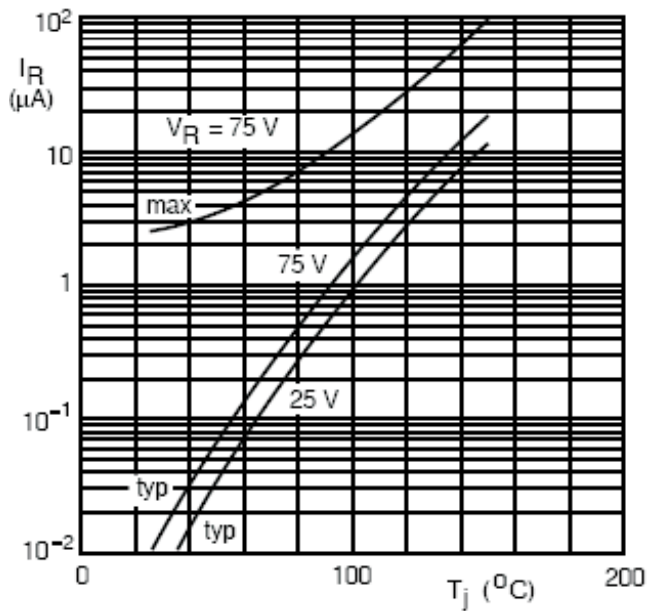
KAV70(BAV70)

Fig.4 Reverse current as a function of junction temperature.

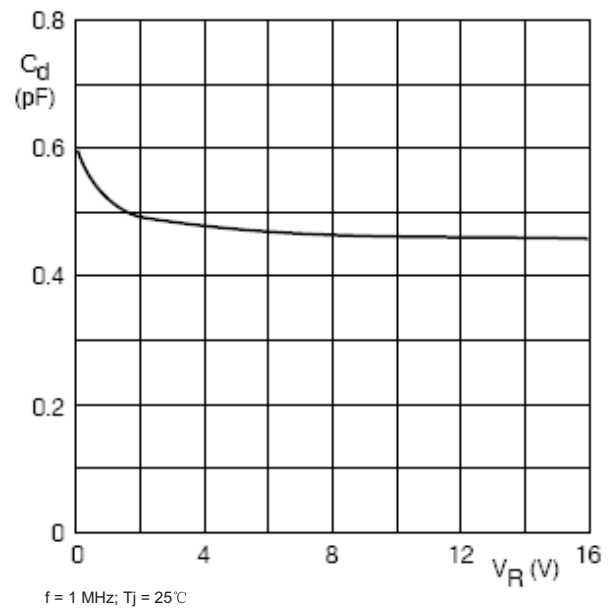


Fig.5 Diode capacitance as a function of reverse voltage; typical values.